

MAGX-001090-700L0x



**GaN on SiC HEMT Pulsed Power Transistor
700 W Peak, 1030 - 1090 MHz, Mode-S ELM**

Rev. V3

Features

- GaN on SiC Depletion-Mode Transistor Technology
- Internally Matched
- Common-Source Configuration
- Broadband Class AB Operation
- 50 V Operation
- RoHS* Compliant and 260 °C Reflow Compatible
- MTTF = 600 years ($T_J < 200$ °C)

Applications

- Civilian Air Traffic Control (ATC)
- Secondary Radar for IFF and Mode-S Avionics.

Description

The MAGX-001090-700L00 and MAGX-001090-700L0S are gold metalized matched Gallium Nitride (GaN) on Silicon Carbide (SiC) RF power transistor optimized for pulsed avionics and radar applications. Using state of the art wafer fabrication processes, these high performance transistors provide high gain, efficiency, bandwidth, and ruggedness over a wide bandwidth for today's demanding application needs. High breakdown voltages allow for reliable and stable operation under more extreme mismatch load conditions compared with older semiconductor technologies.

MAGX-001090-700L00



MAGX-001090-700L0S



Ordering Information¹

Part Number	Description
MAGX-001090-700L00	Standard Flange
MAGX-001090-700L0S	Earless Flange
MAGX-A11090-700L00	1030-1090 MHz Evaluation Board

1. When ordering the evaluation board, please indicate on sales order notes if it will be used for:
 - A. Standard Flange devices
 - B. Earless Flange devices

Typical RF Performance under Standard Operating Conditions, $P_{OUT} = 700$ W (Peak)

Freq (MHz)	P_{IN} (W)	Gain (dB)	I_D (A)	Eff. (%)	RL (dB)	Droop (dB)	+1dB OD (W)	VSWR-S (3:1)	VSWR-T (3:1)
1030	6.1	20.6	20.6	68.0	-13.5	0.25	766	S	P
1060	6.0	20.7	20.4	68.5	-18.4	0.25	760	S	P
1090	6.5	20.3	21.0	66.7	-15.7	0.25	760	S	P

* Restrictions on Hazardous Substances, European Union Directive 2011/65/EU.

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Electrical Specifications: Freq. = 1030 - 1090 MHz, T_A = 25 °C

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Units
Mode-S ELM RF Functional Tests²						
Peak Input Power	$V_{DD} = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, 48 pulses of 32 μs on and 18 μs off, repeat every 24 ms, Overall Duty Factor = 6.4%, $P_{OUT} = 700\text{ W Peak (70 W avg.)}$	P_{IN}	-	6.3	8.5	W
Power Gain		G_P	19.2	20.5	-	dB
Drain Efficiency		η_D	62	67	-	%
Pulse Droop		Droop	-	0.25	0.5	dB
Load Mismatch Stability		VSWR-S	-	3:1	-	-
Load Mismatch Tolerance		VSWR-T	-	3:1	-	-

2. For Mode-S ELM pulse conditions power measurements are obtained as follows:
 RF input / output power is measured at the middle of the 25th pulse in the burst ($t = 1.216\text{ ms}$);
 Droop measurements are defined as the drop in power from the 5th pulse ($t = 216\mu\text{s}$) and 43rd pulse ($t = 2.116\text{ms}$) in the burst.

Electrical Characteristics: T_A = 25°C

Parameter	Test Conditions	Symbol		Typ.		Units
DC Characteristics						
Drain-Source Leakage Current	$V_{GS} = -8\text{ V}$, $V_{DS} = 175\text{ V}$	I_{DS}	-	1.7	-	mA
Gate Threshold Voltage	$V_{DS} = 5\text{ V}$, $I_D = 90\text{ mA}$	$V_{GS(TH)}$	-	-3.1	-	V
Forward Transconductance	$V_{DS} = 5\text{ V}$, $I_D = 21\text{ mA}$	G_M	-	22	-	S
Dynamic Characteristics						
Input Capacitance	Not applicable - Input matched	C_{ISS}	-	N/A	-	pF
Output Capacitance	$V_{DS} = 50\text{ V}$, $V_{GS} = -8\text{ V}$, Freq. = 1 MHz	C_{OSS}	-	55	-	pF
Reverse Transfer Capacitance		C_{RSS}	-	5.5	-	pF

Absolute Maximum Ratings^{3,4,5}

Parameter	Rating
Drain Voltage (V_{DD})	+65 V
Gate Voltage (V_{GG})	-8 to -2 V
Drain Current (I_{DD})	31 A
Input Power ⁶ (P_{IN})	P_{IN} (nominal) + 3 dB
Operating Junction Temperature ⁷	250 °C
Peak Pulsed Power Dissipation at 85 °C	875 W
Operating Temperature Range	-40 to +95 °C
Storage Temperature Range	-65 to +150 °C
ESD Maximum - Charged Device Model (CDM)	1300 V
ESD Maximum - Human Body Model (HBM)	4000 V

3. Exceeding any one or combination of these limits may cause permanent damage to this device.

4. MACOM does not recommend sustained operation near these survivability limits.

5. For saturated performance it is recommended that the sum of $(3 * V_{DD} + |V_{GG}|) < 175$ V.

6. Input Power Limit is +3 dB over nominal drive required to achieve $P_{OUT} = 700$ W.

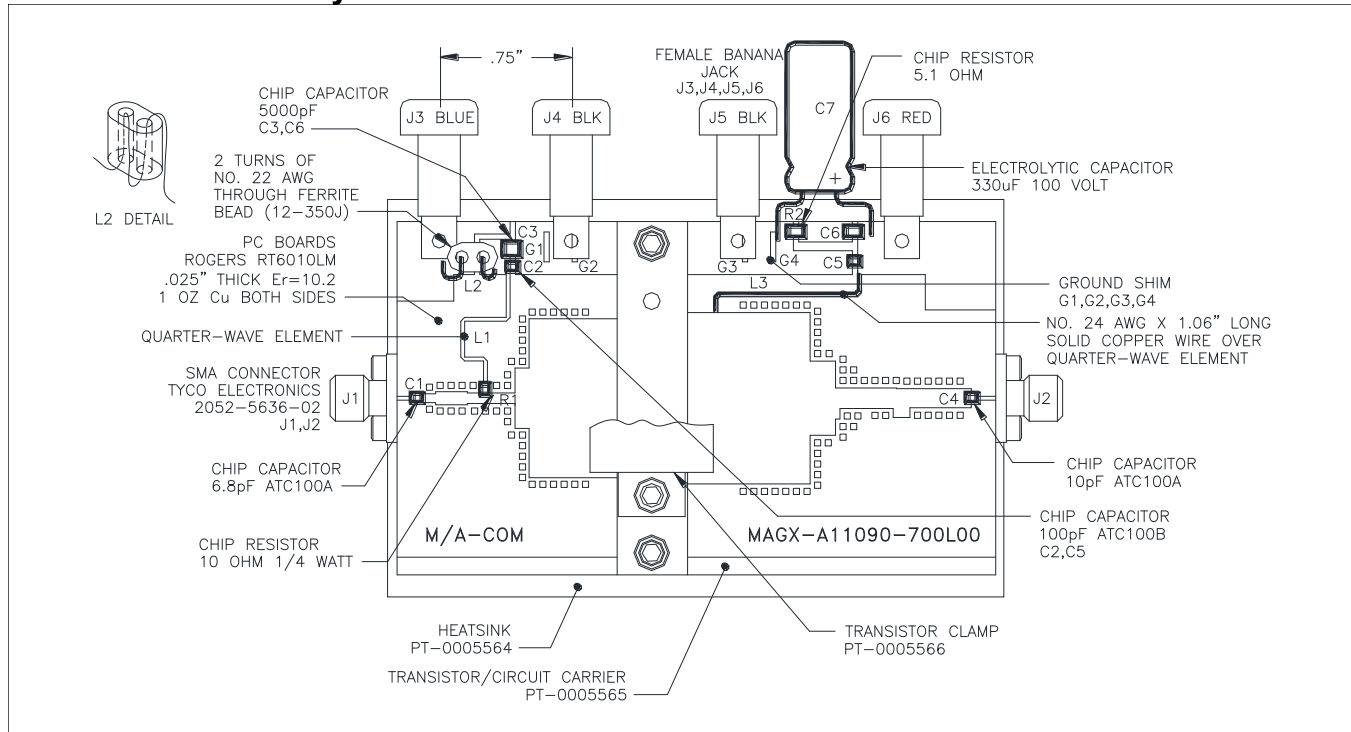
7. Operating junction temperature is measured with infrared (IR) microscope. Junction temperature directly affects a device's MTTF and should be kept as low as possible to maximize lifetime.

- MTTF = 5.3×10^6 hours ($T_J < 200$ °C)
- MTTF = 6.8×10^4 hours ($T_J < 250$ °C)

Thermal Characteristics

Parameter	Test Conditions	Symbol	Typical	Units
Thermal Resistance	$T_C = 70$ °C, $V_{DD} = 50$ V, $I_{DQ} = 500$ mA, $P_{OUT} = 700$ W, 48 pulses of 32 μ s on and 18 μ s off, repeat every 24 ms, Overall Duty Factor = 6.4%,	Θ_{JC}	0.2	°C/W

Test Fixture Assembly



Contact MACOM for additional circuit information.

Test Fixture Impedances

Freq. (MHz)	Z _{IF} (Ω)	Z _{OF} (Ω)
1030	0.7 - j0.4	1.3 + j0.8
1060	0.8 - j0.3	1.4 + j0.7
1090	0.8 - j0.1	1.4 + j0.7

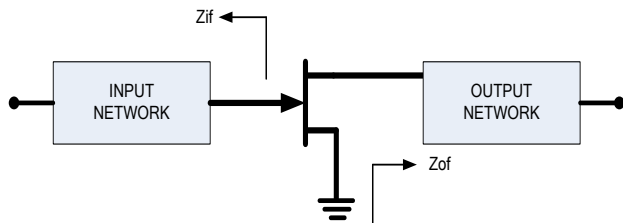
Correct Device Sequencing

Turning the device ON

1. Set V_{GS} to the pinch-off (V_P), typically -5 V.
2. Turn on V_{DS} to nominal voltage (50 V).
3. Increase V_{GS} until the I_{DS} current is reached.
4. Apply RF power to desired level.

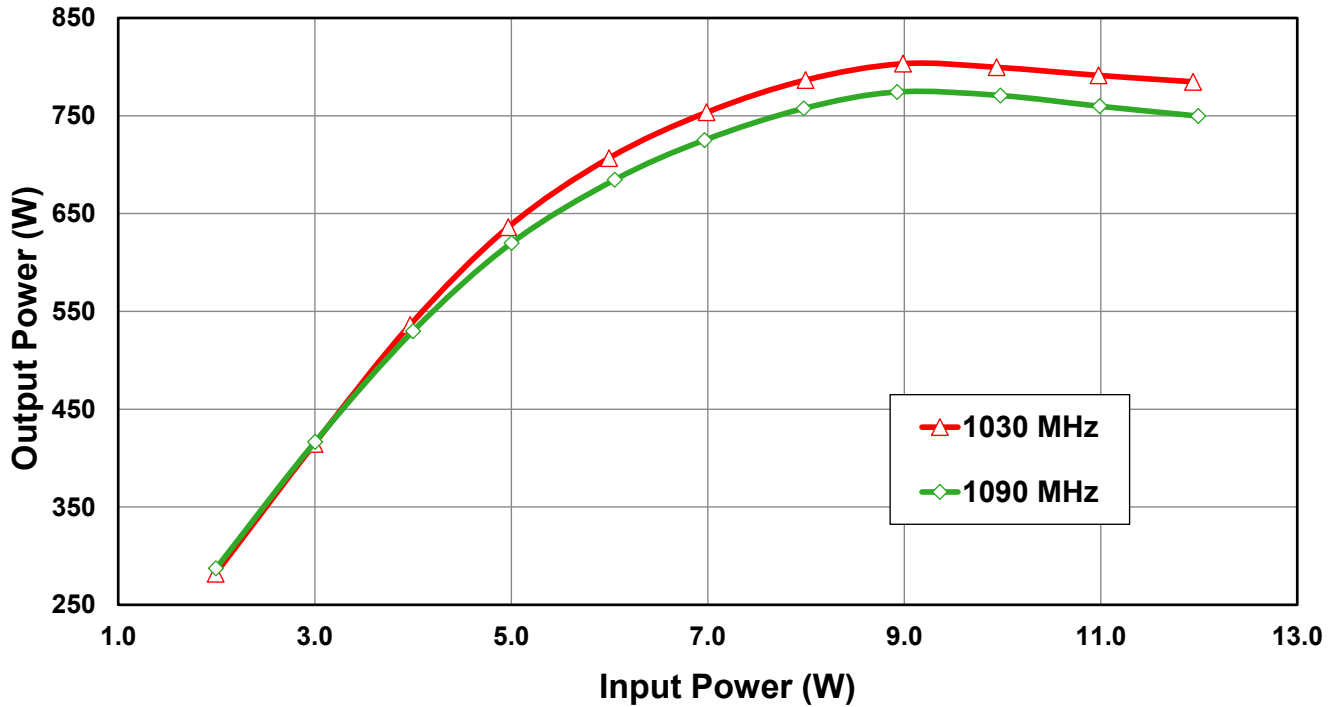
Turning the device OFF

1. Turn the RF power off.
2. Decrease V_{GS} down to V_P .
3. Decrease V_{DS} down to 0 V.
4. Turn off V_{GS} .

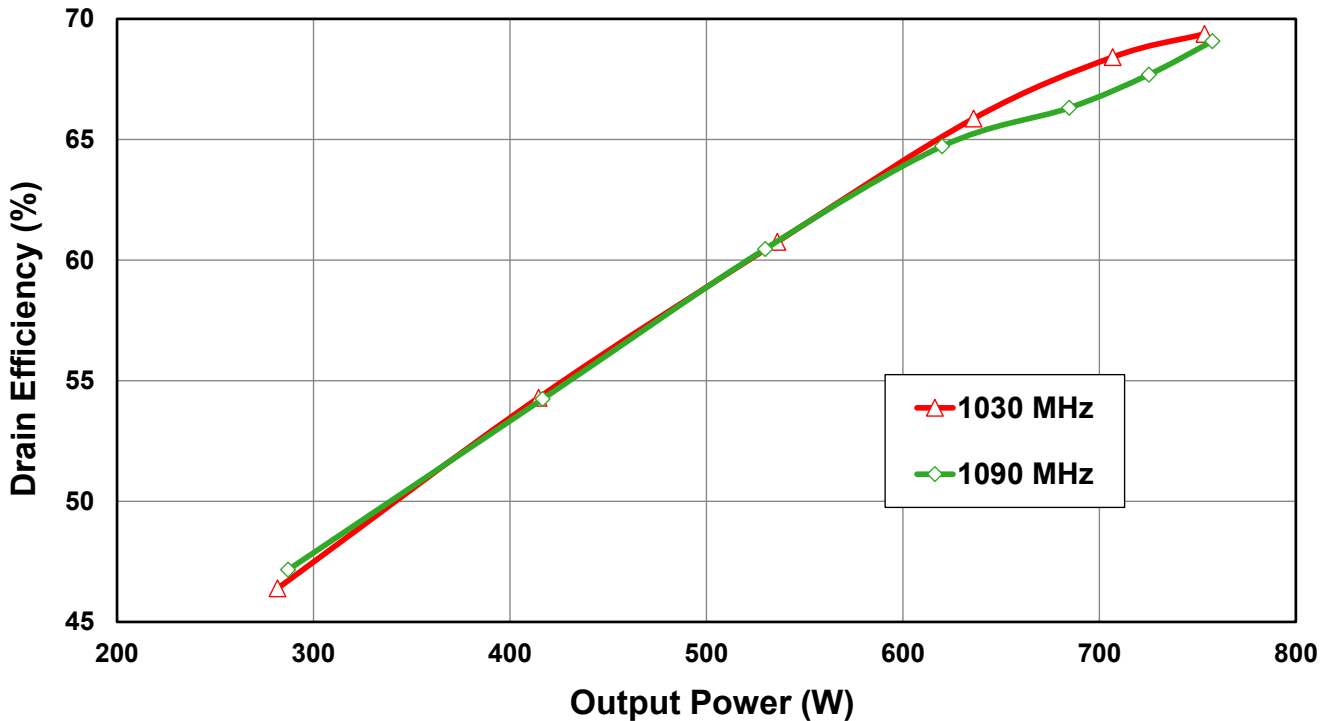


Contact factory for gerber file or additional circuit information.

RF Power Transfer Curve (Output Power vs. Input Power)



RF Power Transfer Curve (Drain Efficiency vs. Output Power)



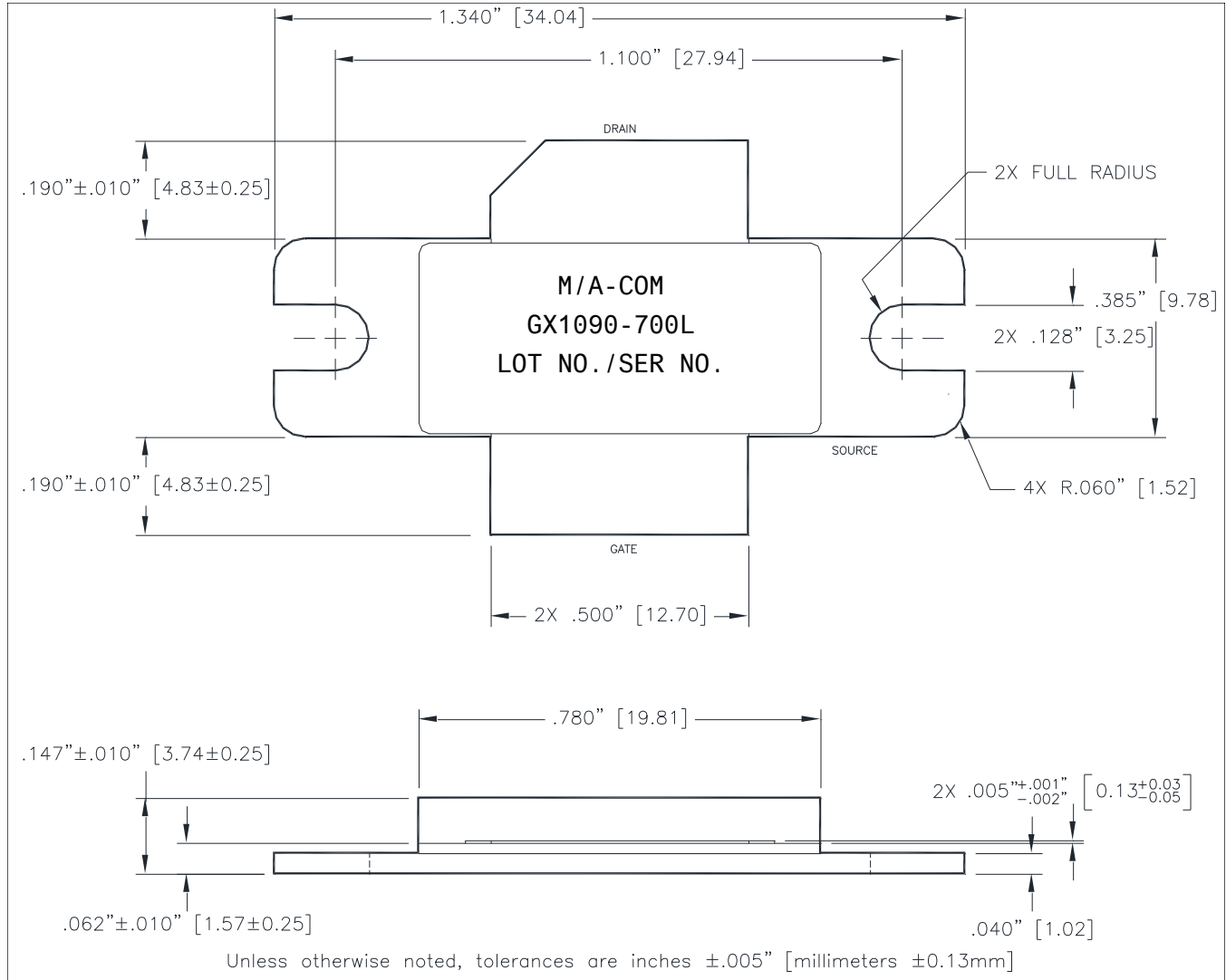
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Outline Drawing MAGX-001090-700L00†



† Reference Application Note AN3025 for mounting/soldering recommendations.
Meets JEDEC moisture sensitivity level 1 requirements.
Plating is Ni/Au.

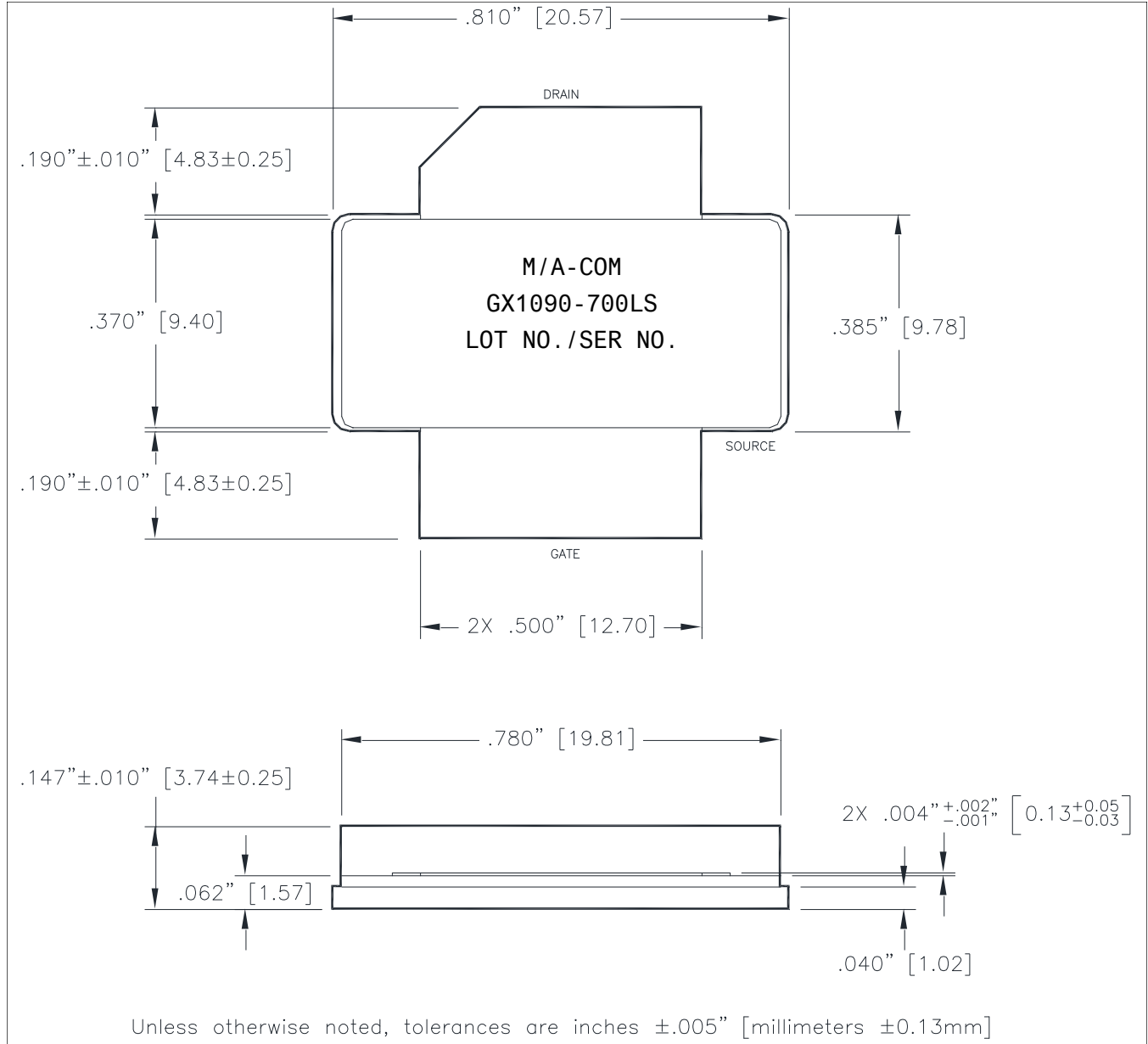
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Outline Drawing MAGX-001090-700L0S†



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Meets JEDEC moisture sensitivity level 1 requirements.
Plating is Ni/Au.

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